

## SD103AW, BW, CW

# SURFACE MOUNT SCHOTTKY BARRIER DIODE

# REVERSE VOLTAGE – 20 to 40 Volts FORWARD CURRENT – 0.35 Ampere

**SOD-123** 

#### **FEATURES**

- Extremely low VF drop
- Guard Ring Construction for Transient protection
- Negligible Reverse Recovery Time

#### **MECHANICAL DATA**

- Case: SOD-123 Plastic
- Case Material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Moisture Sensitivity: Level 1 per J-STD-020D
- Lead Free in RoHS 2002/95/EC Compliant

SOD-123			
Dim.	Min. Max		
Α	2.55	2.85	
В	1.40 1.80		
С	0.95	1.35	
D	050	0.70	
E	0.3 REF		
Н	0.1		
J	0.15		
K	3.55 3.85		
Dimensions in millimeter			

### **Maximum Ratings & Thermal Characteristics** @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	SD103AW	SD103BW	SD103CW	Units
Repetitive Peak reverse voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RM}$	40	30	20	V
RMS Reverse Voltage	$V_R$	28	21	14	
Forward Continuous Current	I <sub>FM</sub>		350		mA
Non-Repetitive Peak Forward Surge Current @t<1.0s	I <sub>FSM</sub>		1.5		Α
Power Dissipation	$P_{D}$		400		mW
Thermal Resistance Junction to Ambient	$R_{\Theta JA}$		313		°C/W
Operating Temperature Range	TJ		125		$^{\circ}\!\mathbb{C}$
Storage Temperature Range	T <sub>STG</sub>		-65~+125		$^{\circ}\!\mathbb{C}$

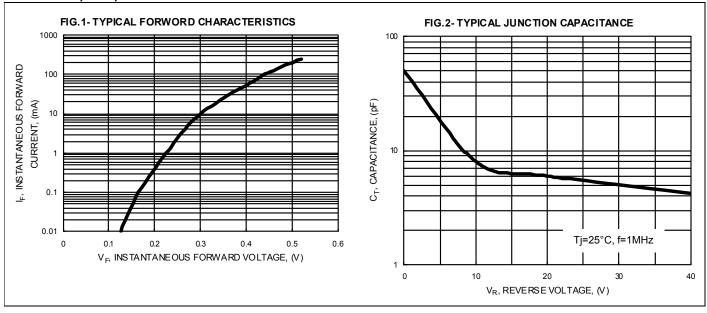
#### Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Test Condition	Symbol	SD103AW	SD103BW	SD103CW	Unit
Reverse Breakdown Voltage	I <sub>R</sub> = 100uA	$V_{BR}$	40	30	20	V
Maximum Forward Voltage	I <sub>F</sub> = 20mA I <sub>F</sub> = 200mA	V <sub>F</sub>		370 600		mV
Maximum DC Reverse Current at Rated DC Blocking Voltage	V <sub>R</sub> = 30V V <sub>R</sub> = 20V V <sub>R</sub> = 10V	I <sub>R</sub>	5  	 5 	  5	uA
Typical Diode Capacitance	V <sub>R</sub> =0V,f=1MHz	C <sub>D</sub>		50		pF
Reverse Recovery time	Irr=20mA, IR=IF=200mA RL=100Ω	trr		10		nS

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# RATING AND CHARACTERISTIC CURVES SD103AW, BW, CW





#### **Device Marking:**

Device P/N	Marking	Equivalent Circuit Diagram
SD103AW	S4	
SD103BW	S5	1 <b>0                                   </b>
SD103CW	S6	



### **Important Notice and Disclaimer**

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### **New Marking Rule Notification**

Range: In order to have well management in process control, the new marking rule is applied to small signal device including Switching Diode, Transistor and Schottky Diode.

Package: SOD-123 / SOD-323 / SOD-523

